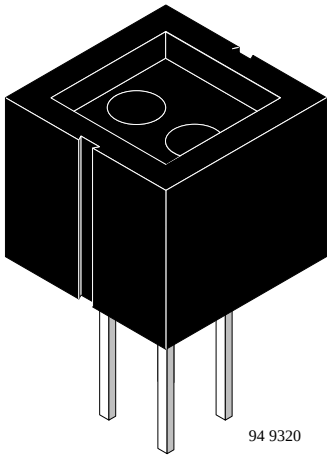
Reflective Optosensor with Transistor Output

Description

The CNY70 has a compact construction where the emitting light source and the detector are arranged in the same direction to sense the presence of an object by using the reflective IR beam from the object.

The operating wavelength is 950 nm. The detector consists of a phototransistor.



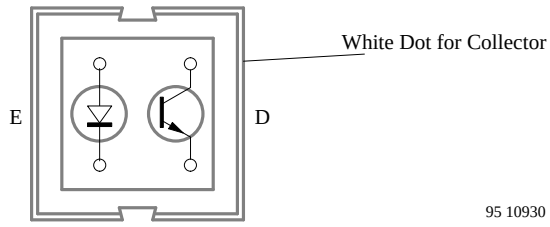
Applications

- Opto-electronic scanning and switching devices i.e., index sensing, coded disk scanning etc. (opto-electronic encoder assemblies for transmission sensing).

Features

- Compact construction in center-to-center spacing of 0.1”
- No setting required
- High signal output
- Low temperature coefficient
- Detector provided with optical filter

Pin Connection



Top view

Absolute Maximum Ratings

Input (Emitter)

Parameters	Test Conditions	Symbol	Value	Unit
Reverse voltage		V_R	5	V
Forward current		I_F	50	mA
Forward surge current	$t_p \leq 10$ µs	I_{FSM}	3	A
Power dissipation	$T_{amb} \leq 25°C$	P_V	100	mW
Junction temperature		T_j	100	°C

Output (Detector)

Parameters	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		V_{CEO}	32	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Power dissipation	$T_{amb} \leq 25°C$	P_v	100	mW
Junction temperature		T_j	100	°C

Coupler

Parameters	Test Conditions	Symbol	Value	Unit
Total power dissipation	$T_{amb} \leq 25°C$	P_{tot}	200	mW
Ambient temperature range		T_{amb}	–55 to +85	°C
Storage temperature range		T_{stg}	–55 to +100	°C
Soldering temperature	2 mm from case, t ≤ 5 s	T_{sd}	260	°C

Electrical Characteristics

T_{amb} = 25°C

Input (Emitter)

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	I_F = 50 mA	V_F		1.25	1.6	V

Output (Detector)

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter voltage	I_C = 1 mA	V_{CEO}	32			V
Emitter collector voltage	I_E = 100 µA	V_{ECO}	5			V
Collector dark current	V_{CE} = 20 V, I_f = 0, E = 0	I_{CEO}			200	nA

Coupler

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector current	V_{CE} = 5 V, I_F = 20 mA, d = 0.3 mm (figure 1)	I_C [1)]	0.3	1.0		mA
Cross talk current	V_{CE} = 5 V, I_F = 20 mA (figure 1)	I_{CX} [2)]			600	nA
Collector emitter saturation voltage	I_C = 0.1 mA, I_F = 20 mA, d = 0.3 mm (figure 1)	V_{CEsat} [1)]			0.3	V

1) Measured with the “Kodak neutral test card”, white side with 90% diffuse reflectance

3) Measured without reflecting medium

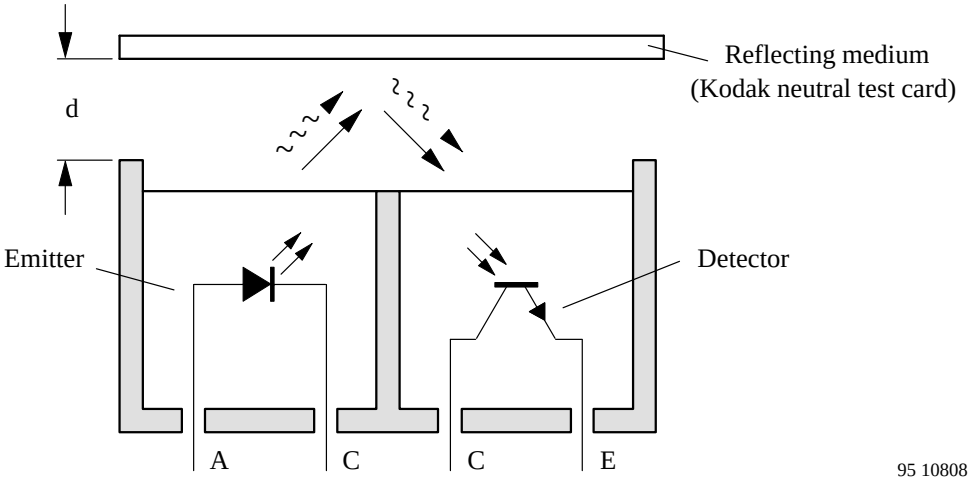


Figure 1. Test circuit

Typical Characteristics (T_{amb} = 25°C, unless otherwise specified)

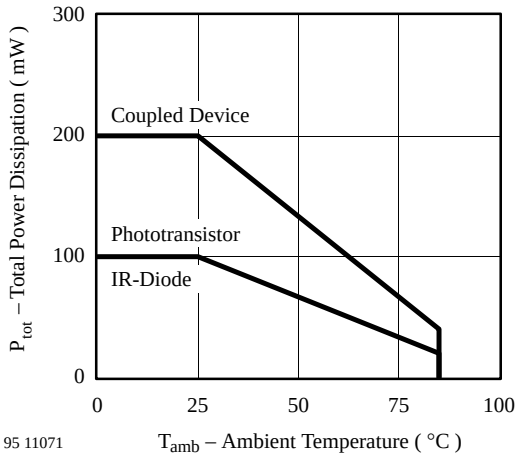


Figure 2. Total Power Dissipation vs. Ambient Temperature

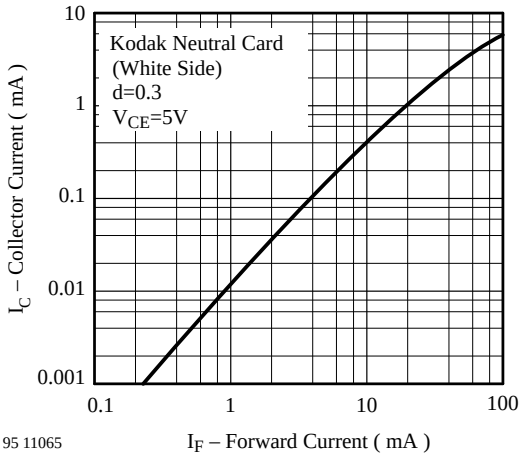


Figure 5. Collector Current vs. Forward Current

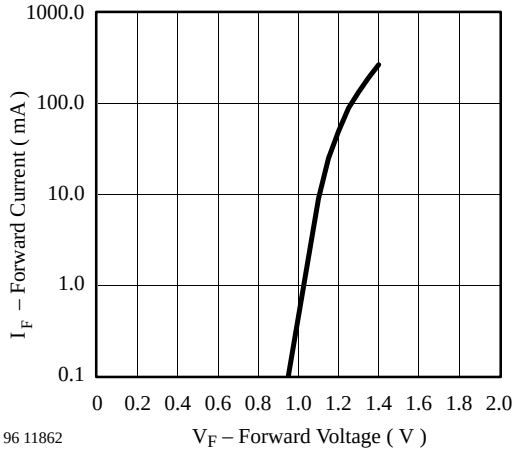


Figure 3. Forward Current vs. Forward Voltage

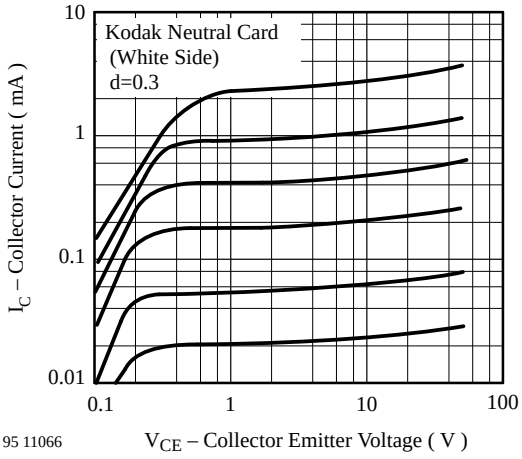


Figure 6. Collector Current vs. Collector Emitter Voltage

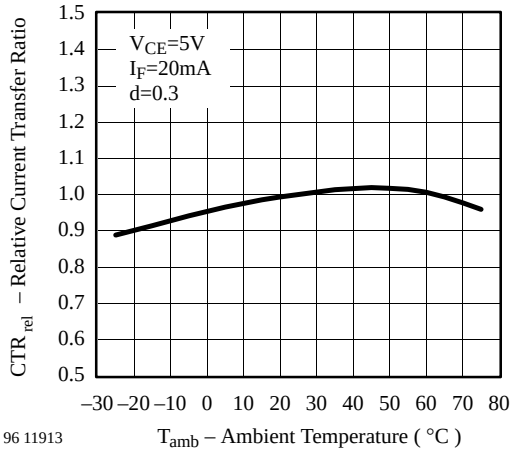


Figure 4. Rel. Current Transfer Ratio vs. Ambient Temperature

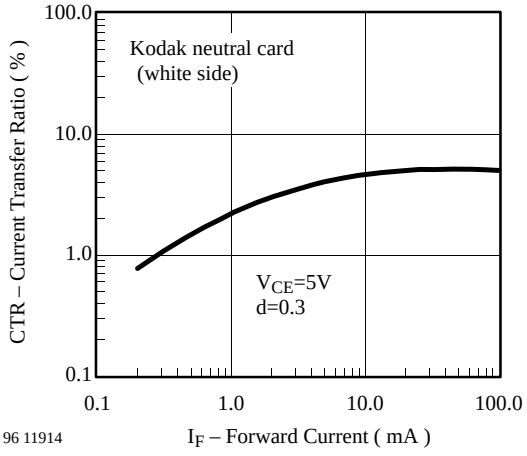


Figure 7. Current Transfer Ratio vs. Forward Current

Typical Characteristics (T_{amb} = 25°C, unless otherwise specified)

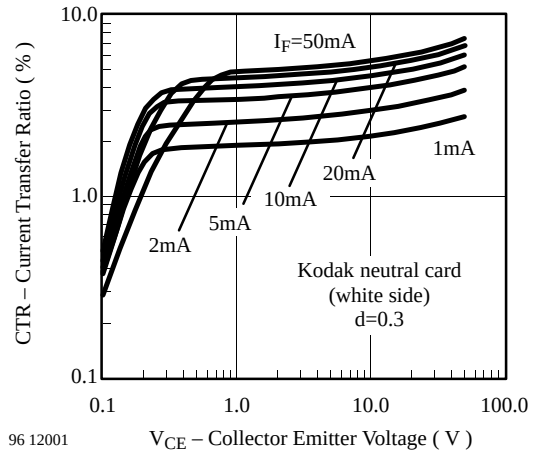


Figure 8. Current Transfer Ratio vs. Collector Emitter Voltage

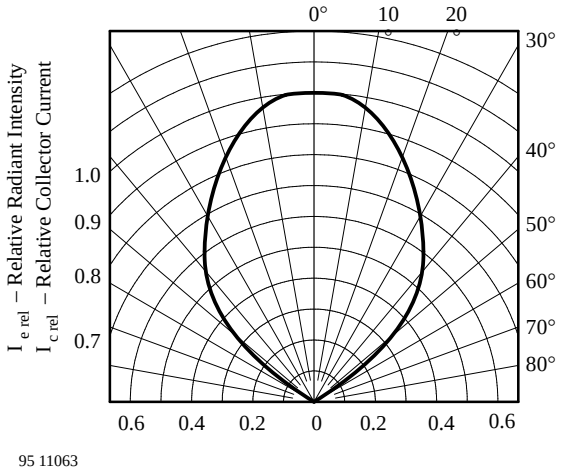


Figure 10. Rel. Rad. Intensity/ Coll. Current vs. Displacement

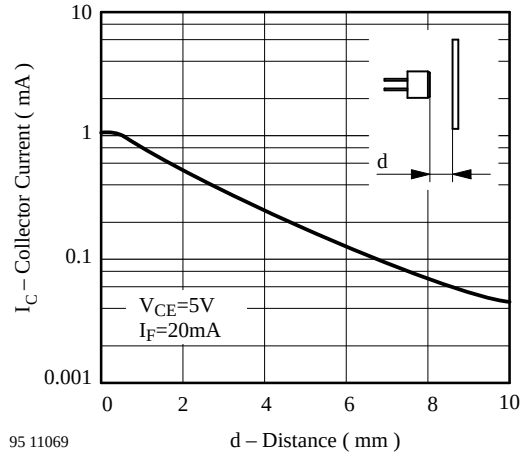


Figure 9. Collector Current vs. Distance

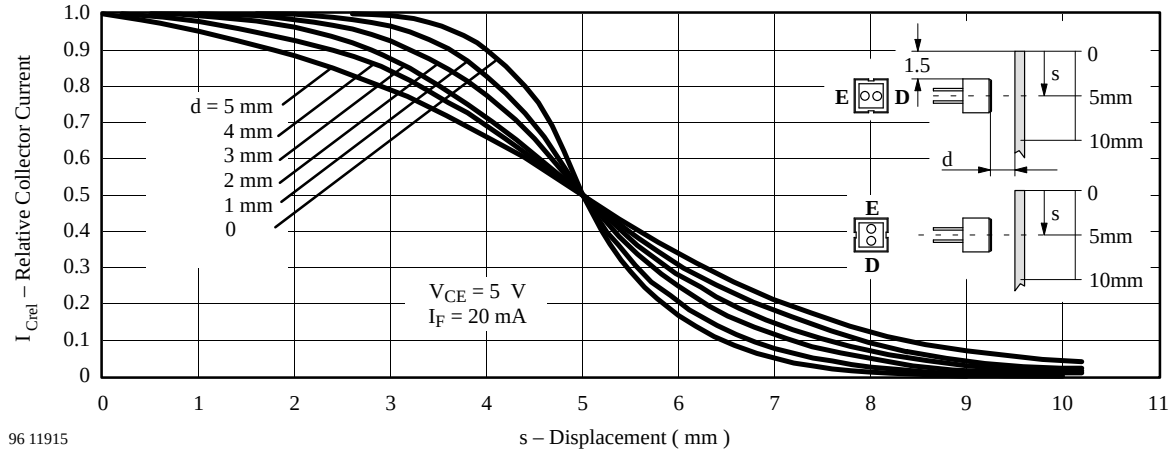
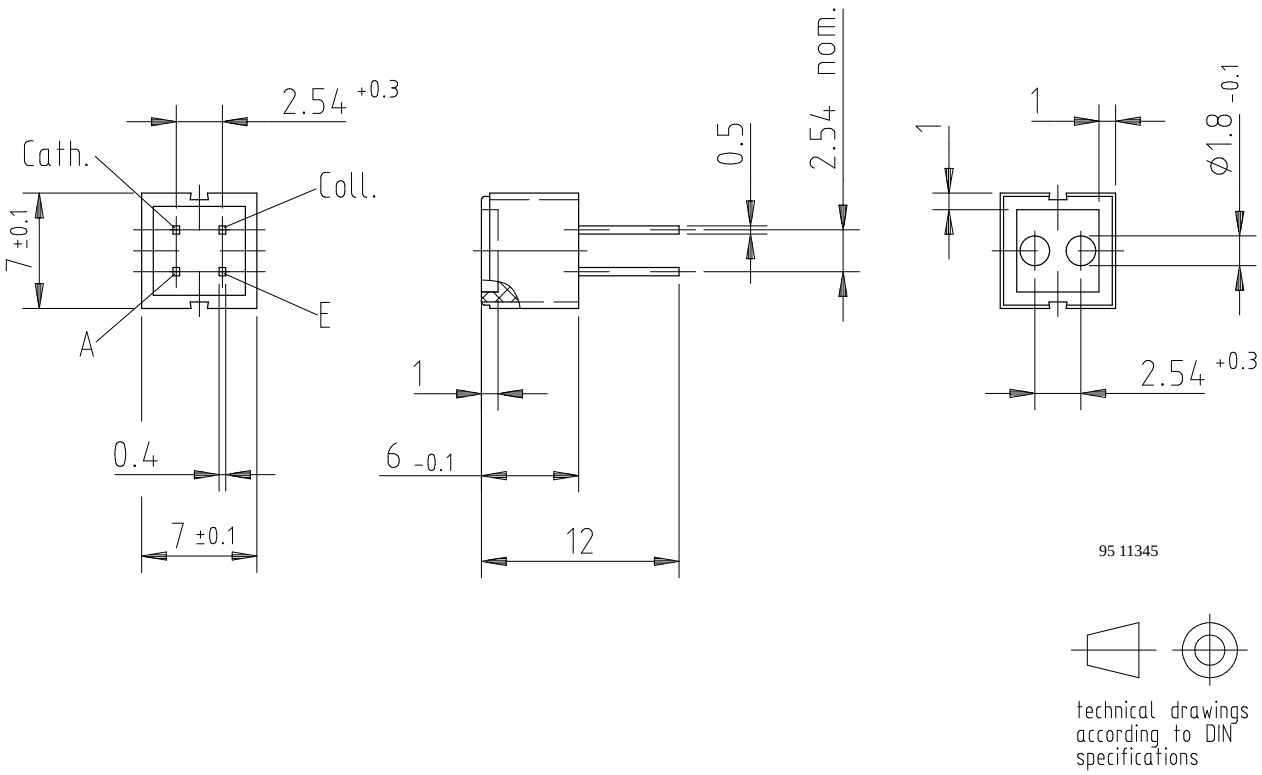


Figure 11. Rel. Collector Current vs. Displacement

Dimensions in mm



weight: ca. 0.70 g

Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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